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With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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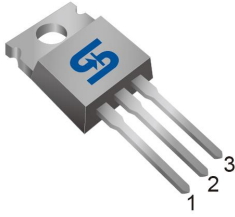
Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



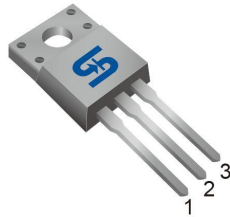
TSM340N06

60V N-Channel Power MOSFET

TO-220



ITO-220



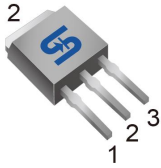
Pin Definition:

1. Gate
2. Drain
3. Source

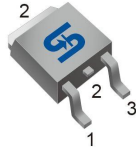
Key Parameter Performance

Parameter	Value	Unit
V_{DS}	60	V
$R_{DS(on)}$ (max)	$V_{GS} = 10V$	34
	$V_{GS} = 4.5V$	40
Q_g	16.6	nC

TO-251S
(IPAK)



TO-252
(DPAK)

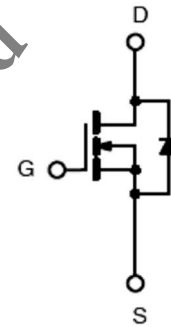


Ordering Information

Part No.	Package	Packing
TSM340N06CI C0G	ITO-220	50pcs / Tube
TSM340N06CZ C0G	TO-220	50pcs / Tube
TSM340N06CH X0G	TO-251S	75pcs / Tube
TSM340N06CP ROG	TO-252	2.5kpcs / 13 Reel

Note: 'G' denotes for Halogen- and Antimony-free as those which contain
<900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and
<1000ppm antimony compounds

Block Diagram



N-Channel MOSFET

Absolute Maximum Ratings (T_c = 25°C unless otherwise noted)

Parameter	Symbol	Limit			Unit
		IPAK/DPAK	ITO-220	TO-220	
Drain-Source Voltage	V_{DS}	60			V
Gate-Source Voltage	V_{GS}	±20			V
Continuous Drain Current ^(Note 1)	I_D	30			A
		19			A
Pulsed Drain Current ^(Note 2)	I_{DM}	120			A
Single Pulse Avalanche Energy ^(Note 3)	E_{AS}	24			mJ
Single Pulse Avalanche Current ^(Note 2)	I_{AS}	22			A
Total Power Dissipation @ T _c = 25°C	P_D	40	27	66	W
Operating Junction Temperature	T_J	150			°C
Storage Temperature Range	T_{STG}	-55 to +150			°C

Thermal Performance

Parameter	Symbol	Limit			Unit
		IPAK/DPAK	ITO-220	TO-220	
Thermal Resistance - Junction to Case	$R_{\theta JC}$	3.1	4.7	1.9	°C/W
Thermal Resistance - Junction to Ambient	$R_{\theta JA}$	62			°C/W

Electrical Specifications ($T_C = 25^\circ\text{C}$ unless otherwise noted)

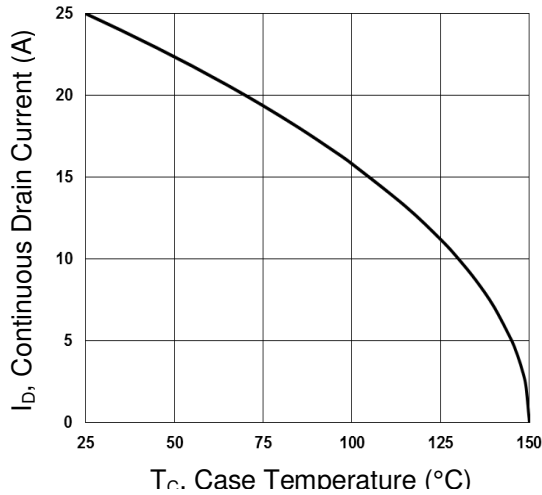
Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	BV_{DSS}	60	--	--	V
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 15A$	$R_{DS(ON)}$	--	28	34	m
	$V_{GS} = 4.5V, I_D = 10A$		--	33	40	
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	$V_{GS(TH)}$	1.2	1.7	2.5	V
Zero Gate Voltage Drain Current	$V_{DS} = 60V, V_{GS} = 0V$	I_{DSS}	--	--	1	μA
	$V_{DS} = 48V, T_J = 125^{\circ}C$		--	--	10	
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	I_{GSS}	--	--	± 100	nA
Forward Transconductance	$V_{DS} = 10V, I_D = 8A$	g_{fs}	--	8	--	S
Dynamic						
Total Gate Charge (Note 4,5)	$V_{DS} = 30V, I_D = 20A, V_{GS} = 10V$	Q_g	--	16.6	--	nC
Gate-Source Charge (Note 4,5)		Q_{GS}	--	2.2	--	
Gate-Drain Charge (Note 4,5)		Q_{gd}	--	3.9	--	
Input Capacitance	$V_{DS} = 30V, V_{GS} = 0V, f = 1MHz$	C_{iss}	--	1180	--	pF
Output Capacitance		C_{oss}	--	68	--	
Reverse Transfer Capacitance		C_{rss}	--	45	--	
Gate Resistance	$V_{GS}=0V, V_{DS}=0V, f=1MHz$	R_g	--	2.1	--	
Switching						
Turn-On Delay Time (Note 4,5)	$V_{DD}=30V, V_{GS}=10V, R_G=6\Omega, I_D=-1A$	$t_{d(on)}$	--	4.6	--	ns
Turn-On Rise Time (Note 4,5)		t_r	--	14.8	--	
Turn-Off Delay Time (Note 4,5)		$t_{d(off)}$	--	27.2	--	
Turn-Off Fall Time (Note 4,5)		t_f	--	7.8	--	
Source-Drain Diode Ratings and Characteristic						
Continuous Drain-Source Diode	$V_G=V_D=0V$, Force Current	I_S	--	--	25	A
Pulse Drain-Source Diode		I_{SM}	--	--	100	A
Diode-Source Forward Voltage	$V_{GS} = 0V, I_S = 1A$	V_{SD}	--	--	1	V
Reverse Recovery Time (Note 4)	$V_{GS} = 0V, I_S = 1A$	t_{rr}	--	17	--	ns
Reverse Recovery Charge (Note 4)	$dl_F/dt = 100A/\mu s$	Q_{rr}	--	12	--	nC

Note:

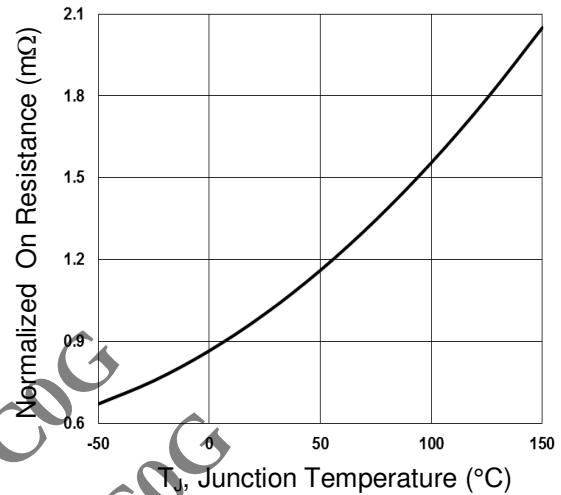
- Limited by maximum junction temperature
- Pulse width limited by safe operating area
- $L = 0.1\text{mH}$, $I_{AS} = 22A$, $V_{DD} = 50V$, $R_G = 25\Omega$, Starting $T_J = 25^\circ\text{C}$
- Pulse test: pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$
- Switching time is essentially independent of operating temperature.

Electrical Characteristics Curve

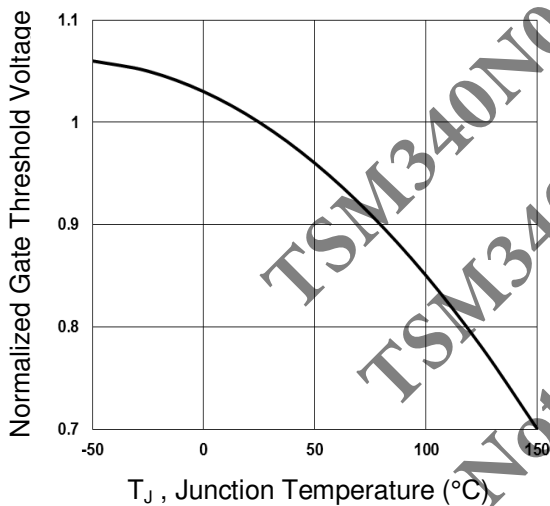
Continuous Drain Current vs. T_c



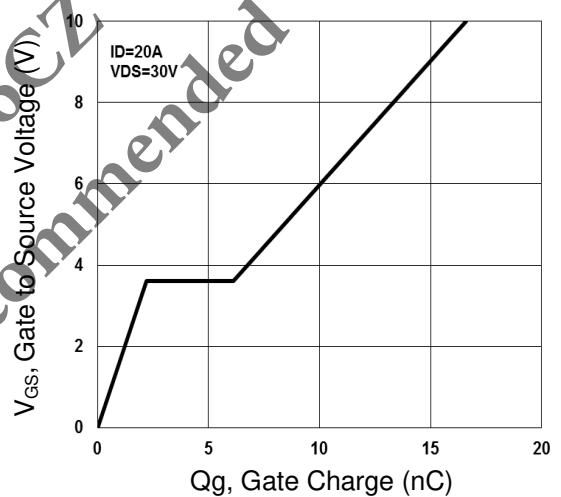
Normalized $R_{DS(on)}$ vs. T_J



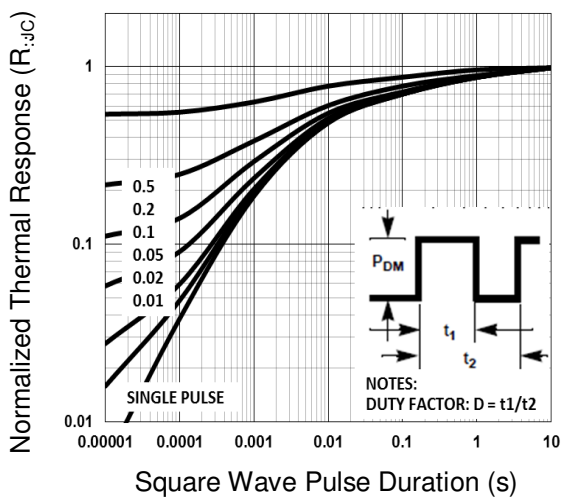
Normalized V_{th} vs. T_J



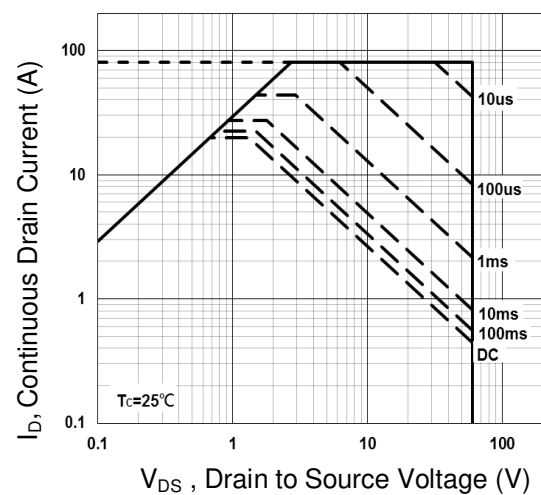
Gate Charge Waveform



Normalized Transient Impedance (ITO-220)

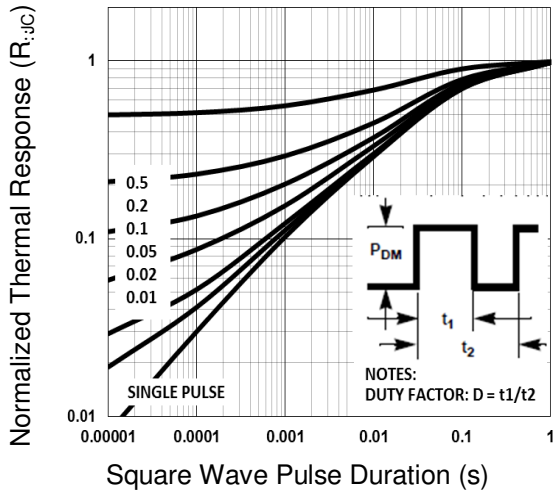


Maximum Safe Operation Area (ITO-220)

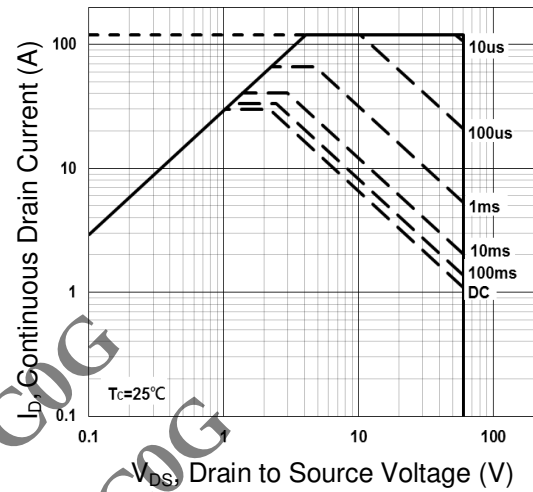


Electrical Characteristics Curve

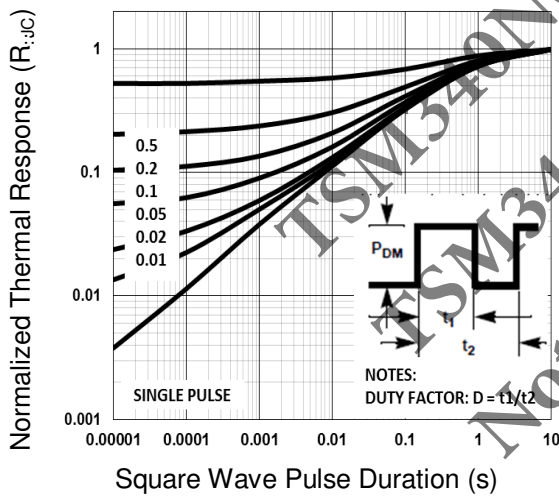
Normalized Transient Impedance (TO-220)



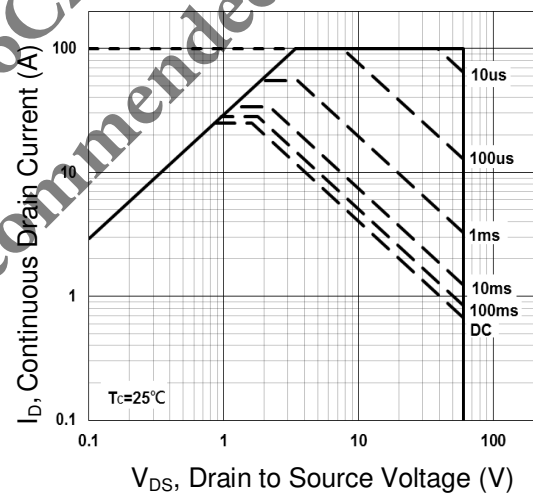
Maximum Safe Operation Area (TO-220)



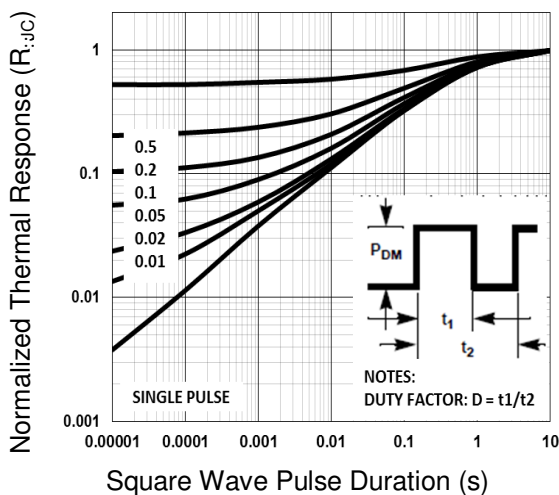
Normalized Transient Impedance (TO-251S)



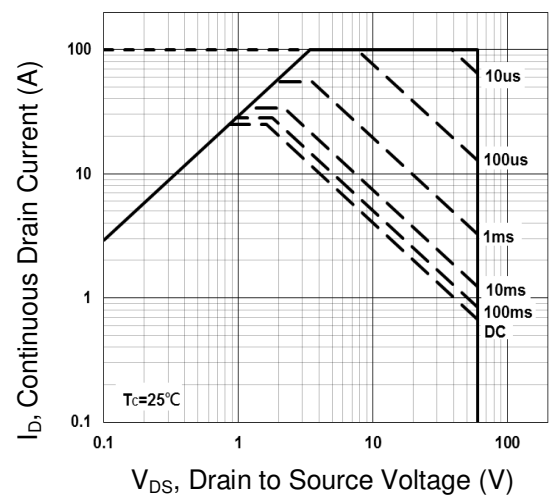
Maximum Safe Operation Area (TO-251S)



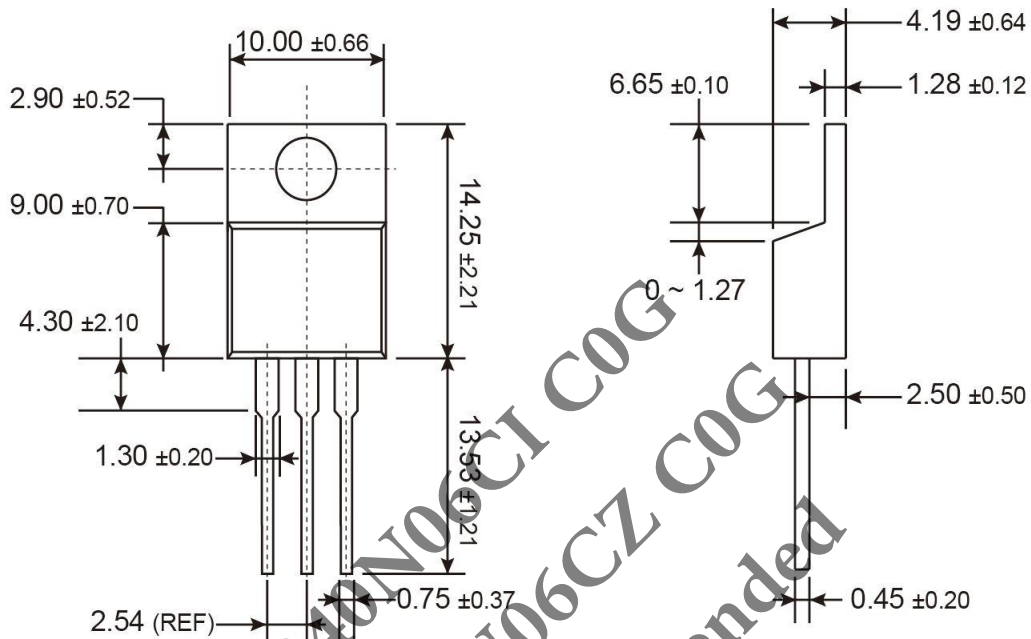
Normalized Transient Impedance (TO-252)



Maximum Safe Operation Area (TO-252)

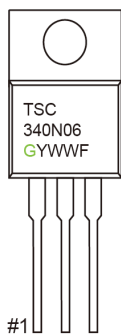


TO-220 Mechanical Drawing



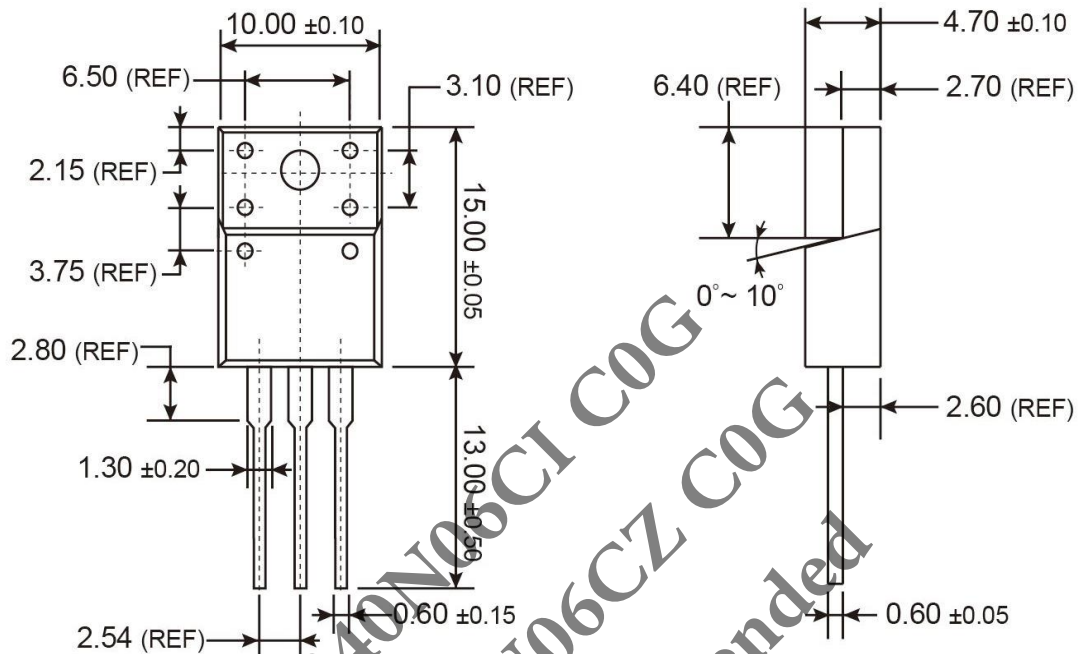
Unit: Millimeters

Marking Diagram



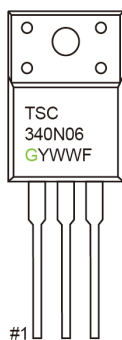
- G** = Halogen Free
- Y** = Year Code
- WW** = Week Code (01~52)
- F** = Factory Code

ITO-220 Mechanical Drawing



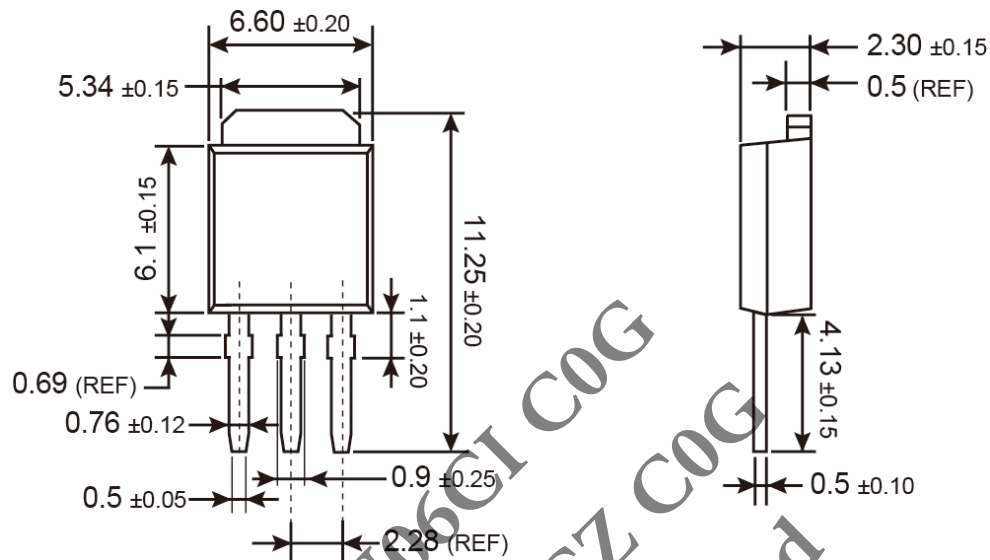
Unit: Millimeters

Marking Diagram



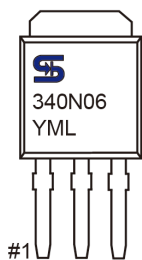
G = Halogen Free
Y = Year Code
WW = Week Code (01~52)
F = Factory Code

TO-251S Mechanical Drawing



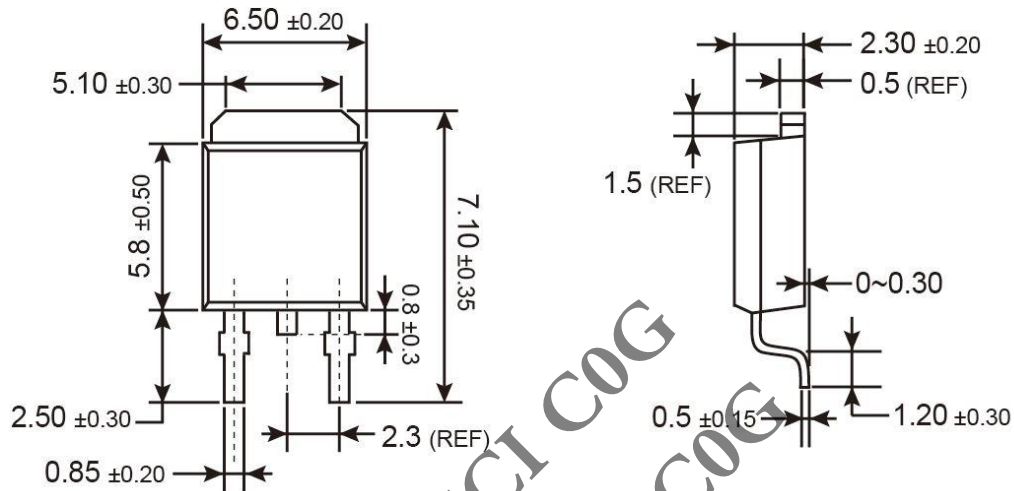
Unit: Millimeters

Marking Diagram



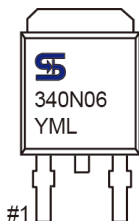
- Y** = Year Code
- M** = Month Code for Halogen Free Product
(**O**=Jan, **P**=Feb, **Q**=Mar, **R**=Apr, **S**=May, **T**=Jun, **U**=Jul, **V**=Aug, **W**=Sep, **X**=Oct, **Y**=Nov, **Z**=Dec)
- L** = Lot Code

TO-252 Mechanical Drawing



Unit: Millimeters

Marking Diagram



Y = Year Code

M = Month Code for Halogen Free Product

(**O**=Jan, **P**=Feb, **Q**=Mar, **R**=Apr, **S**=May, **T**=Jun, **U**=Jul, **V**=Aug, **W**=Sep, **X**=Oct, **Y**=Nov, **Z**=Dec)

L = Lot Code

TSM340N06

60V N-Channel Power MOSFET

TSM340N06CI C0G
TSM340N06CZ C0G
Not Recommended

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